

FGR3000FX-90DA

HIGH POWER INVERTER USE
PRESS PACK TYPE

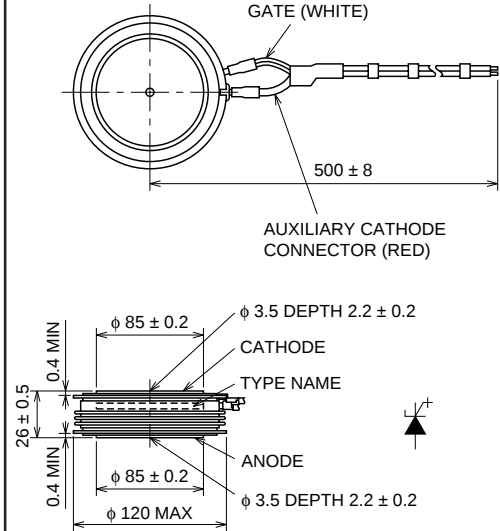
FGR3000FX-90DA



- ITQRM Repetitive controllable on-state current 3000A
- IT(AV) Average on-state current 780A
- VDRM Repetitive peak off state voltage 4500V
- Reverse conducting type

OUTLINE DRAWING

Dimensions in mm



APPLICATION

Inverters, D.C. choppers, Induction heaters, D.C. to D.C. converters.

MAXIMUM RATINGS

Symbol	Parameter	Voltage class	Unit
		90DA	
VDRM	Repetitive peak off-state voltage*	4500	V
VDSM	Non-repetitive peak off-state voltage*	4500	V
VD(DC)	DC off-state voltage*	3600	V
VLDS	Long term DC stability voltage*	3000	V

* : VGK = -2V

Symbol	Parameter	Conditions	Ratings	Unit
ITQRM	Repetitive controllable on-state current	V _{DM} = 4500V, T _j = 125°C, C _s = 6.0μF, L _s = 0.2μH	3000	A
IT(RMS)	RMS on-state current		1220	A
IT(AV)	Average on-state current	f = 60Hz, sine wave θ = 180°, T _f = 70°C	780	A
ITSM	Surge (non-repetitive) on-state current	One half cycle at 60Hz	16	kA
IT ² _t	I ² t for fusing	One cycle at 60Hz	1.0 × 10 ⁶	A ² s
IR(RMS)	RMS Reverse current		940	A
IR(AV)	Average reverse current	f = 60Hz, sine wave θ = 180°C, T _f = 75°C	600	A
IRSM	Surge (non-repetitive) reverse current	One half cycle at 60Hz	16	kA
IR ² _t	Current-squared, time integration	One cycle at 60Hz	1.0 × 10 ⁶	A ² s
diT/dt	Critical rate of rise of on-state current	V _D = 3000V, I _{GM} = 75A, T _j = 75°C	500	A/μs
VFGM	Peak forward gate voltage		10	V
VRGM	Peak reverse gate voltage		18	V
IFGM	Peak forward gate current		100	A
IRGM	Peak gate reverse current		900	A
PFGM	Peak forward gate power dissipation		400	W
PRGM	Peak reverse gate power dissipation		27	kW
PFG(AV)	Average forward gate power dissipation		100	W
PRG(AV)	Average reverse gate power dissipation		230	W
T _j	Junction temperature		-40 ~ +125	°C
T _{stg}	Storage temperature		-40 ~ +150	°C
—	Mounting force required	Recommended value 37	31 ~ 43	kN
—	Weight	Standard value	1450	g

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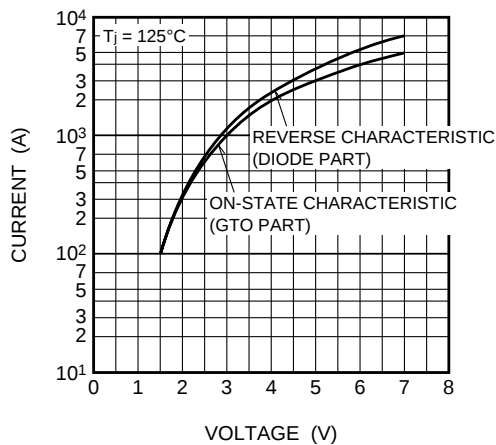
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ELECTRICAL CHARACTERISTICS

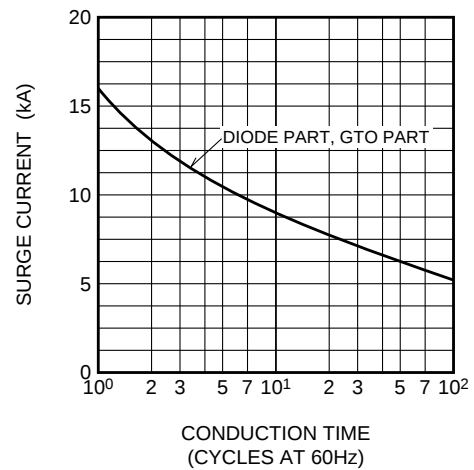
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V _{TM}	On-state voltage	T _J = 125°C, I _{TM} = 3000A, Instantaneous measurment	—	—	5.0	V
V _{RM}	Peak reverse voltage drop	T _J = 125°C, I _{RM} = 3000A, Instantaneous measurment	—	—	4.5	V
I _{DRM}	Repetitive peak off-state current	T _J = 125°C, V _{DRM} Applied, V _{GK} = -2V	—	—	250	mA
I _{RG}	Reverse gate current	T _J = 125°C, V _{RG} = 17V	—	—	500	mA
dv/dt	Critical rate of rise of off-state voltage	T _J = 125°C, V _D = 3000V, V _{GK} = -2V	1000	—	—	V/μs
t _{gt}	Turn-on time	T _J = 125°C, I _{TM} = 3000A, I _{GM} = 75A, V _D = 3000V	—	—	10	μs
t _{gq}	Turn-off time	T _J = 125°C, I _{TM} = 3000A, V _{DM} = 4500V, diGQ/dt = -30A/μs V _{RG} = 17V, C _S = 6.0μF, L _S = 0.2μH	—	—	30	μs
I _{GQM}	Peak gate turn-off current		—	720	—	A
V _{GT}	Gate trigger voltage	DC METHOD : V _D = 24V, R _L = 0.1Ω, T _J = 25°C	—	—	1.5	V
I _{GT}	Gate trigger current		—	—	3000	mA
R _{th(j-f)}	Thermal resistance	GTO Side (Junction to fin)	—	—	0.016	°C/W
		Diode Side (Junction to fin)	—	—	0.025	

PERFORMANCE CURVES

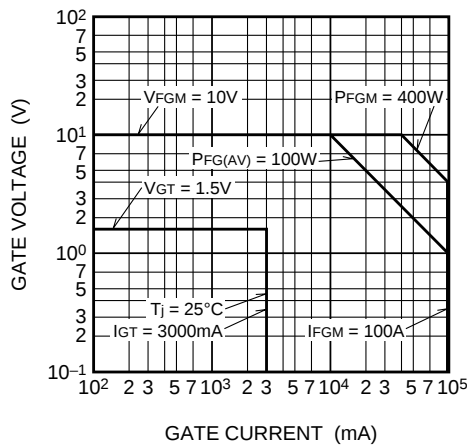
MAXIMUM ON-STATE AND MAXIMUM
REVERSE CHARACTERISTICS



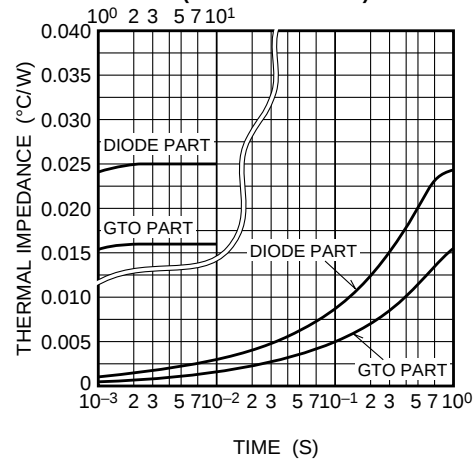
RATED ON-STATE AND REVERSE
SURGE CURRENT



GATE CHARACTERISTICS



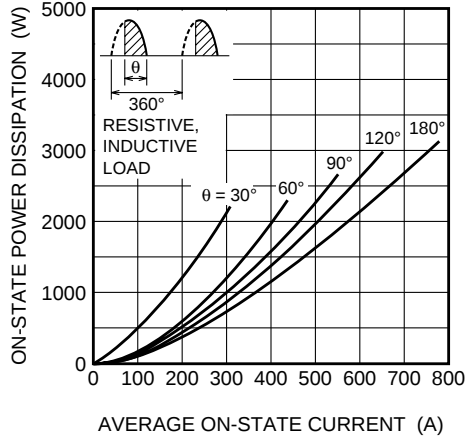
MAXIMUM THERMAL IMPEDANCE
CHARACTERISTICS
(JUNCTION TO FIN)



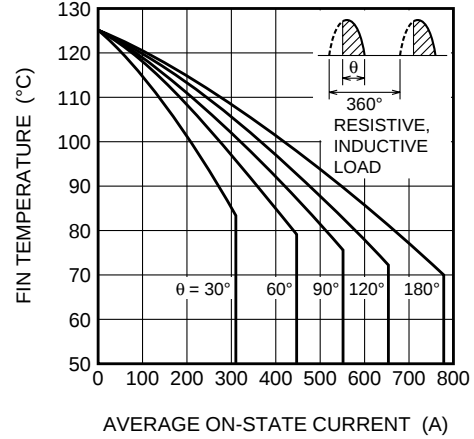
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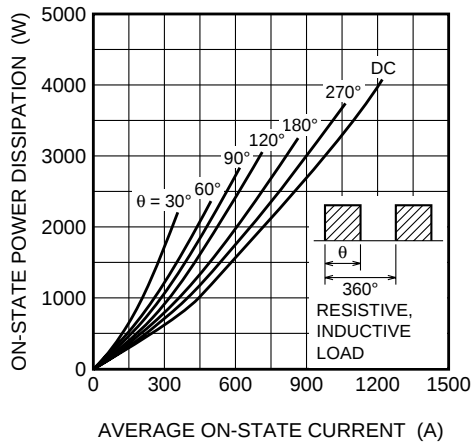
MAXIMUM ON-STATE POWER DISSIPATION CHARACTERISTICS (GTO PART, SINGLE-PHASE HALF WAVE)



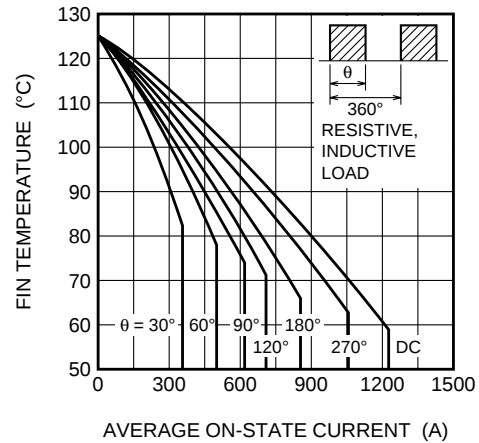
ALLOWABLE FIN TEMPERATURE VS. AVERAGE ON-STATE CURRENT (GTO PART, SINGLE-PHASE HALF WAVE)



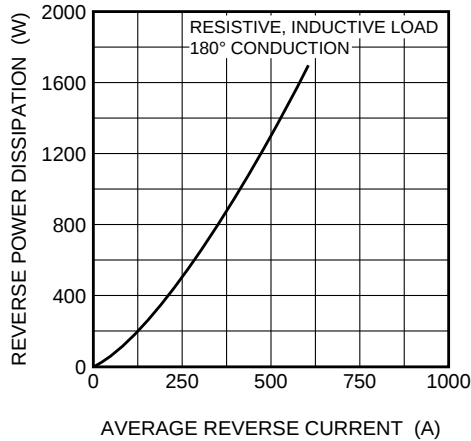
MAXIMUM ON-STATE POWER DISSIPATION CHARACTERISTICS (GTO PART, RECTANGULAR WAVE)



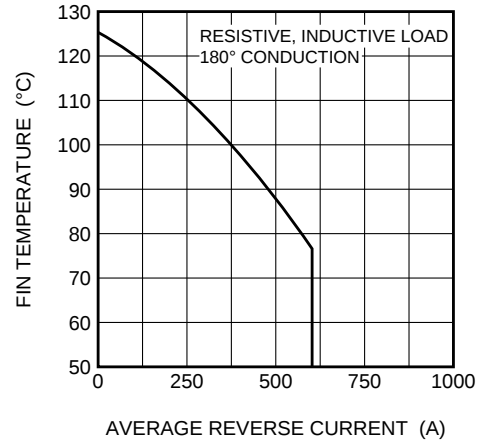
ALLOWABLE FIN TEMPERATURE VS. AVERAGE ON-STATE CURRENT (GTO PART, RECTANGULAR WAVE)



MAXIMUM REVERSE POWER DISSIPATION CHARACTERISTICS (DIODE PART, SINGLE PHASE WAVE)



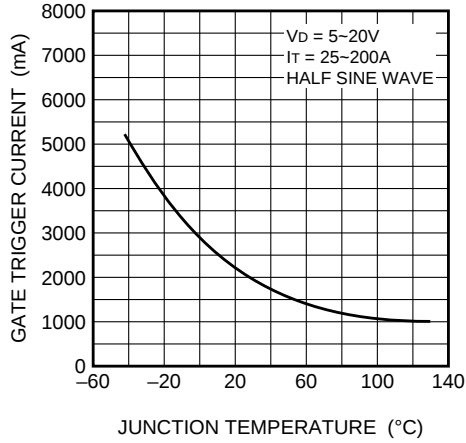
ALLOWABLE FIN TEMPERATURE VS. AVERAGE REVERSE CURRENT (DIODE PART, SINGLE PHASE HALF WAVE)



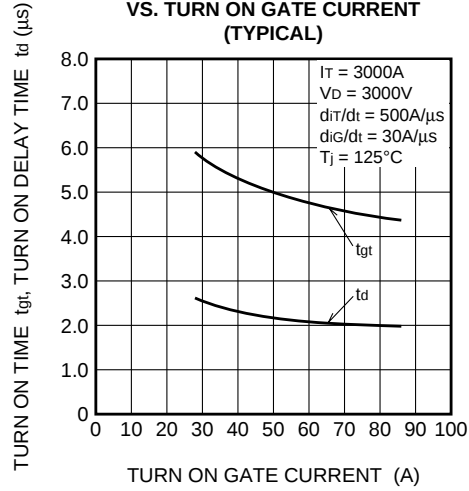
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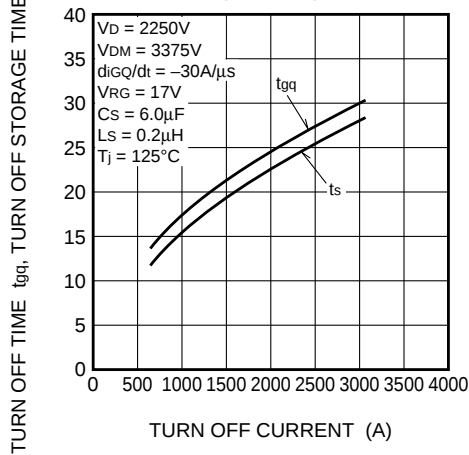
**GATE TRIGGER CURRENT VS.
JUNCTION TEMPERATURE
(TYPICAL)**



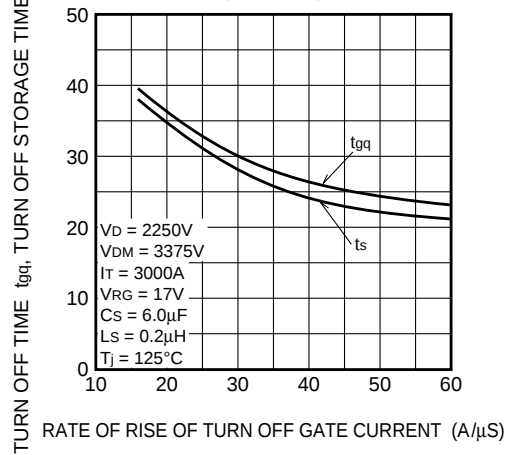
**TURN ON TIME, TURN ON DELAY TIME
VS. TURN ON GATE CURRENT
(TYPICAL)**



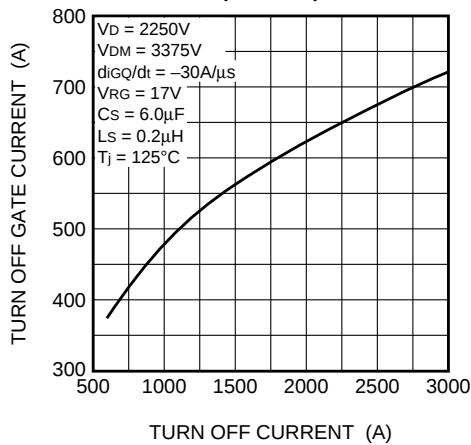
**TURN OFF TIME, TURN OFF STORAGE TIME
VS. TURN OFF GATE CURRENT
(TYPICAL)**



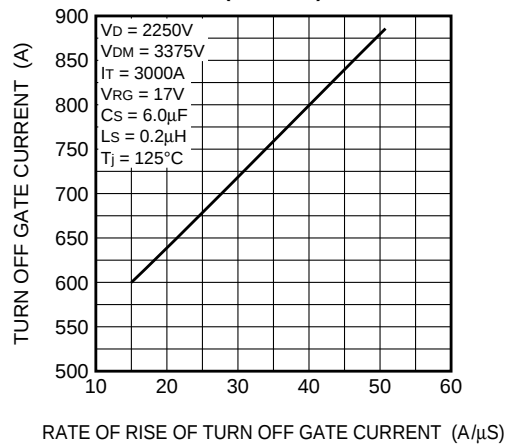
**TURN OFF TIME, TURN OFF STORAGE TIME
VS. RATE OF RISE OF TURN OFF GATE CURRENT
(TYPICAL)**



**TURN OFF GATE CURRENT
VS. TURN OFF CURRENT
(TYPICAL)**



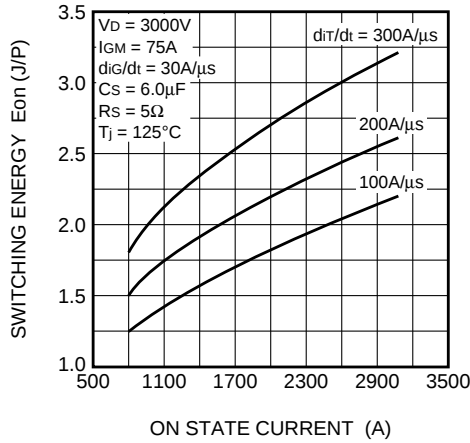
**TURN OFF GATE CURRENT VS.
RATE OF RISE OF GATE CURRENT
(TYPICAL)**



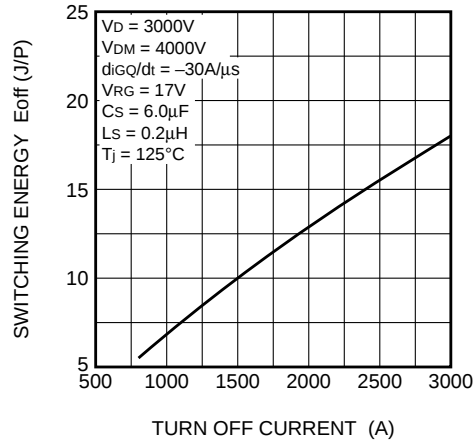
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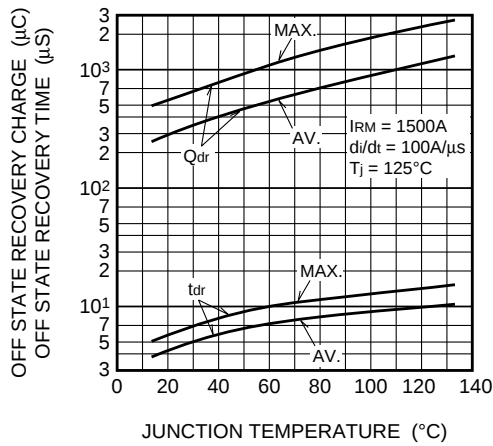
TURN ON SWITCHING ENERGY
(MAXIMUM)



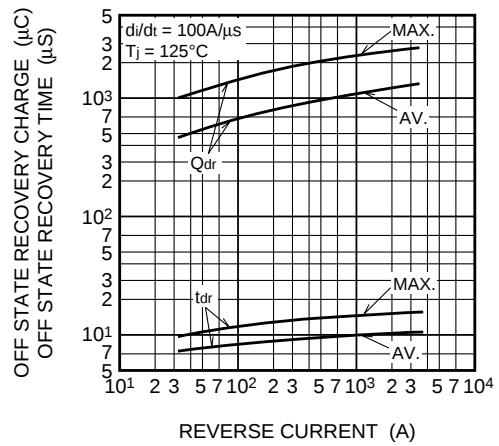
TURN OFF SWITCHING ENERGY
(MAXIMUM)



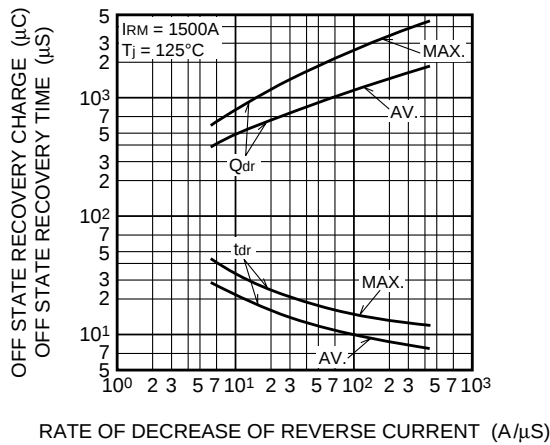
OFF STATE RECOVERY CHARGE,
OFF STATE RECOVERY TIME
VS. JUNCTION TEMPERATURE



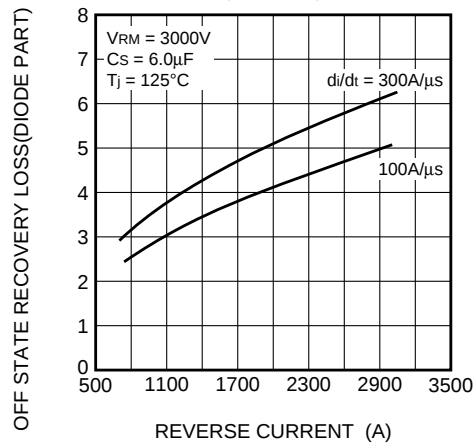
OFF STATE RECOVERY CHARGE,
OFF STATE RECOVERY TIME
VS. REVERSE CURRENT



OFF STATE RECOVERY CHARGE,
OFF STATE RECOVERY TIME
VS. RATE OF DECREASE OF REVERSE CURRENT



OFF STATE RECOVERY LOSS(DIODE PART)
VS. REVERSE CURRENT
(TYPICAL)





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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